

## isc P-Channel MOSFET Transistor

# SPD30P06P

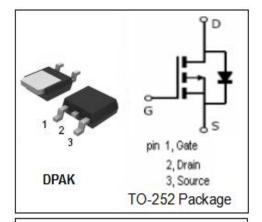
#### ·FEATURES

- Static drain-source on-resistance:
  R<sub>D</sub>s(on)≤75mΩ(@V<sub>S</sub>s= -10V; I<sub>D</sub>= -21.5A)
- · Advanced trench process technology
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

• Fast switching application.



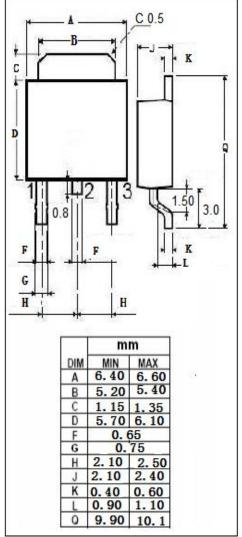


## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	-60	V
$V_{GS}$	Gate-Source Voltage	±20	V
Ι <sub>D</sub>	Drain Current-Continuous	-30	Α
P <sub>D</sub>	Total Dissipation @Tc=25°C	125	W
Tj	Max. Operating Junction Temperature	-55~175	$^{\circ}$
T <sub>stg</sub>	Storage Temperature -55~175		$^{\circ}$

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	1.2	°C/W



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = -250uA	-60		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> = -1.7mA	-2.1	-4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = -10V; I <sub>D</sub> = -21.5A		75	$m\Omega$
Igss	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V; V <sub>DS</sub> = 0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = -60V; V <sub>GS</sub> = 0V		-1	μА
$V_{SD}$	Diode forward voltage	I <sub>S</sub> = -30A, V <sub>GS</sub> = 0V		-1.7	V



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